

FRED

Ultrafast Soft Recovery Diode, 30 A



FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Ver low I_{RRM}
- Ver low Q_{rr}
- Compliant to RoHS
- Designed and qualified for industrial level

N-30ETU06



N-30ATU06

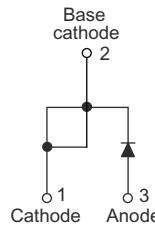


BENEFITS

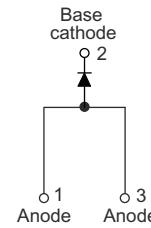
- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

30ETU06 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600V and 30 A continuous current, the 30ETU06 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the FRED product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The FRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These FRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The FRED 30ETU06 is ideally suited for applications in power supplies and conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.



TO-220AC



TO-220AB

PRODUCT SUMMARY

| | |
|-----------------------|----------------|
| V_R | 600 V |
| V_F at 30A at 25 °C | 1.8 V |
| $I_{F(AV)}$ | 30 A |
| t_{rr} (typical) | 23 ns |
| T_J (maximum) | 150 °C |
| Q_{rr} | 55 nC |
| $dI_{(rec)M}/dt$ | 260 A/ μ s |

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
|--|----------------|-----------------|-------------|-------|
| Cathode to anode voltage | V_R | | 600 | V |
| Maximum continuous forward current | I_F | $T_C = 116$ °C | 30 | |
| Single pulse forward current | I_{FSM} | $T_C = 25$ °C | 300 | A |
| Maximum repetitive forward current | I_{FRM} | | 110 | |
| Maximum power dissipation | P_D | $T_C = 25$ °C | 145 | W |
| | | $T_C = 100$ °C | 57 | |
| Operating junction and storage temperature range | T_J, T_{Stg} | | - 55 to 150 | °C |

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| ELECTRICAL SPECIFICATIONS ($T_J = 25^\circ\text{C}$ unless otherwise specified) | | | | | | | |
|---|----------|--|--|------|------|------|---------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V_{BR} | $I_R = 100 \mu\text{A}$ | | 600 | - | - | V |
| Maximum forward voltage | V_{FM} | $I_F = 30 \text{ A}$ | | - | 1.40 | 1.80 | |
| | | $I_F = 60 \text{ A}$ | | - | 1.70 | 2.0 | |
| | | $I_F = 30 \text{ A}, T_J = 125^\circ\text{C}$ | | - | 1.10 | 1.35 | |
| Maximum reverse leakage current | I_{RM} | $V_R = V_R \text{ rated}$ | | - | - | 10 | μA |
| | | $T_J = 150^\circ\text{C}, V_R = V_R \text{ rated}$ | | - | - | 1000 | |
| Junction capacitance | C_T | $V_R = 200\text{V}$ | | - | 35 | - | pF |
| Series inductance | L_S | Measured lead to lead 5 mm from package body | | - | 8 | - | nH |

| DYNAMIC RECOVERY CHARACTERISTICS PERLEG ($T_J = 25^\circ\text{C}$ unless otherwise specified) | | | | | | | |
|---|-------------------|---|---|------|------|------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Reverse recovery time | t_{rr} | $I_F = 0.5\text{A}, I_R = 1.0\text{A}, I_{RR} = 250\text{mA}$ (RG#1 CKT) | | - | 30 | 35 | ns |
| | | $I_F = 1.0 \text{ A}, dI_F/dt = -100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}, T_J = 25^\circ\text{C}$ | | - | 23 | - | |
| | t_{rr1} | $T_J = 25^\circ\text{C}$ | $I_F = 30\text{A}$ $dI_F/dt = -200 \text{ A}/\mu\text{s}$ $V_R = 400 \text{ V}$ | - | 30 | 60 | |
| Peak recovery current | I_{RRM1} | $T_J = 125^\circ\text{C}$ | | - | 175 | 125 | A |
| | I_{RRM2} | $T_J = 25^\circ\text{C}$ | | - | 3 | 6.0 | |
| | I_{RRM2} | $T_J = 125^\circ\text{C}$ | | - | 6 | 10 | |
| Reverse recovery charge | Q_{rr1} | $T_J = 25^\circ\text{C}$ | $V_R = 400 \text{ V}$ | - | 55 | 180 | nC |
| | Q_{rr2} | $T_J = 125^\circ\text{C}$ | | - | 485 | 600 | |
| Peak rate of fall of recovery current during t_b | $dl_{(rec)M}/dt1$ | $T_J = 25^\circ\text{C}$ | | - | 260 | - | $\text{A}/\mu\text{s}$ |
| | $dl_{(rec)M}/dt2$ | $T_J = 125^\circ\text{C}$ | | - | 160 | - | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|--|------------|--|--|----------|------|------------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Lead temperature | T_{lead} | 0.063" from case (1.6 mm) for 10 s | | - | - | 300 | °C |
| Thermal resistance, junction to case | R_{thJC} | | | - | 0.5 | 0.8 | K/W |
| Thermal resistance, junction to ambient | R_{thJA} | Typical socket mount | | - | - | 80 | |
| Thermal resistance, case to heatsink | R_{thCS} | Mounting surface, flat, smooth and gerased | | - | 0.4 | - | |
| Weight | | | | - | 2 | - | g |
| | | | | - | 0.07 | - | oz. |
| Mounting torque | | | | 6 (5) | - | 12 (10) | kgf . cm (lbf . in) |
| Marking device | | Case style TO-220AC | | 30ETU06 | | | |
| | | Case style TO-220AB | | 30ATU06 | | | |

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Fig.1 Typical forward voltage drop characteristics

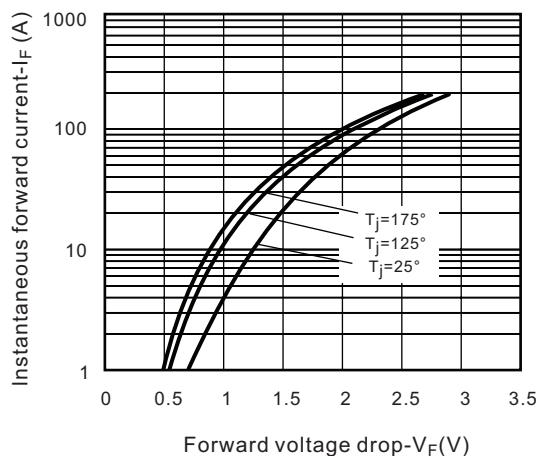


Fig.2 Typical values of reverse current vs. reverse voltage

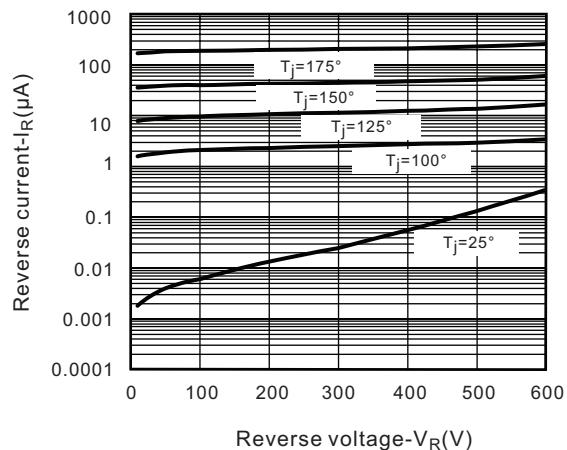


Fig.3 Typical junction capacitance vs. reverse voltage

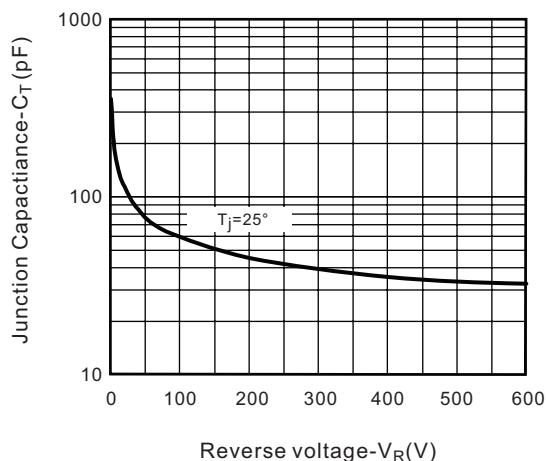


Fig.4 Junction capacitance vs. reverse voltage

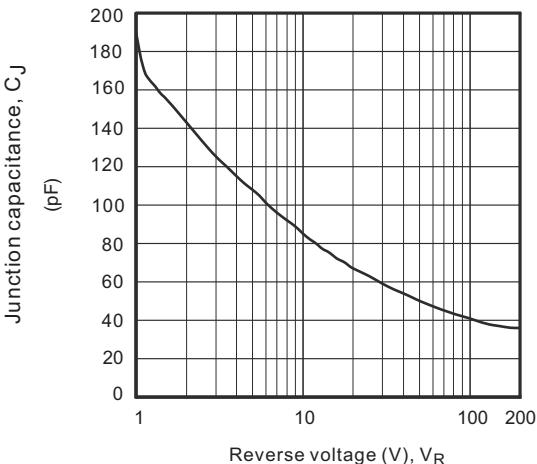
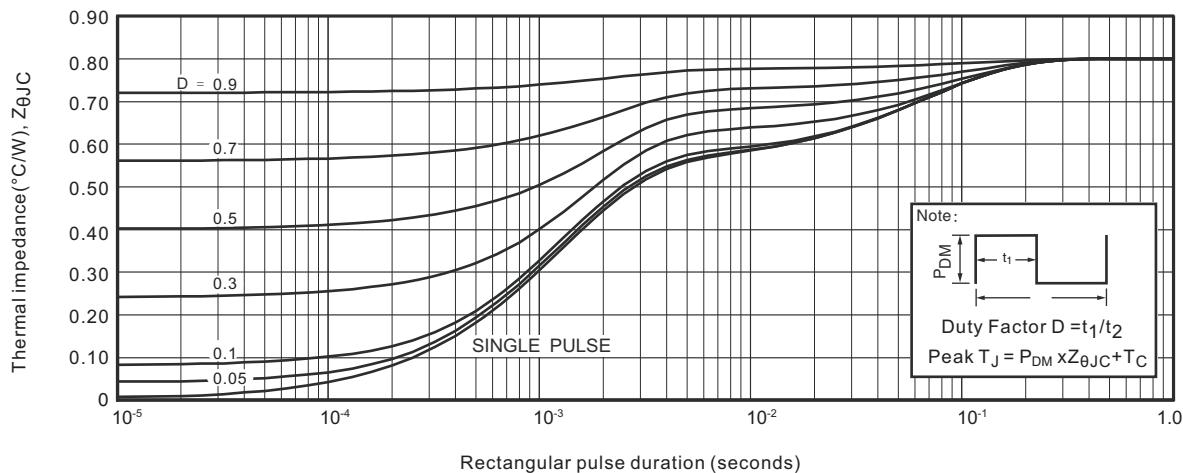


Fig.5 Maximum effective transient thermal impedance, junction-to-case vs. pulse duration



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Fig.6 Max. allowable case temperature Vs. average forward current

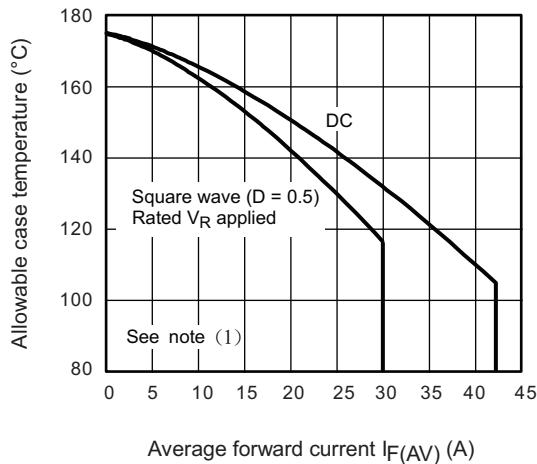


Fig.7 Reverse recovery time vs. current rate of change

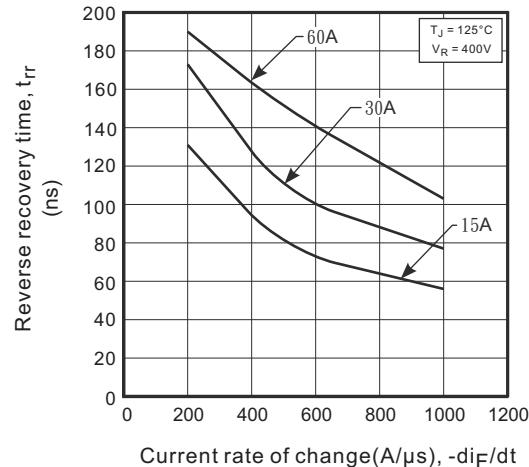


Fig.8 Maximum average forward current vs. case temperature

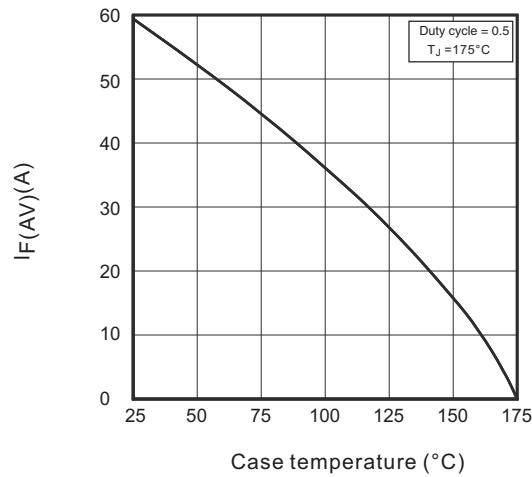
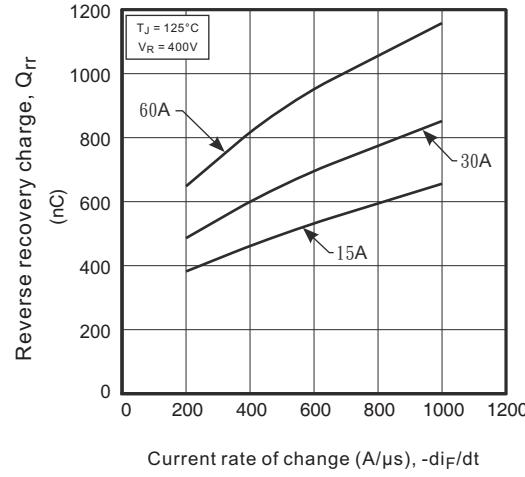


Fig.9 Reverse recovery charge vs. current rate of change



Ordering Information Table

Device code

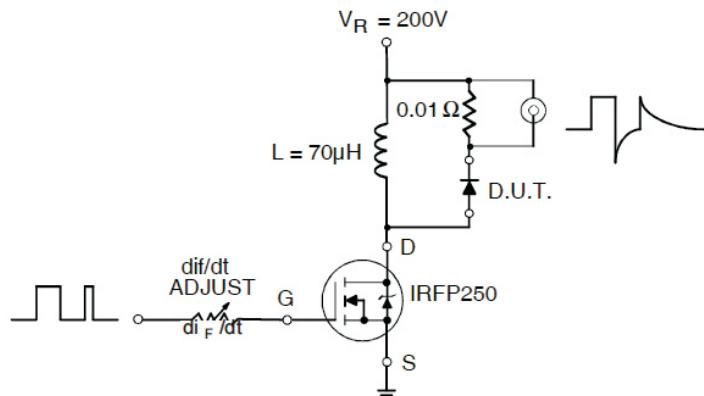
| | | | | | | |
|----------|----------|-----------|----------|----------|----------|-----------|
| N | - | 30 | E | T | U | 06 |
| (1) | (2) | (3) | (4) | (5) | (6) | |

- 1 - Nell
- 2 - Current rating (30 = 30A)
- 3 - Single Diode
- 4 - TO-220AC or TO-220AB
- 5 - Ultrafast Recovery
- 6 - Voltage Rating (06 = 600 V)

E = 2 pins
A = 3 pins

Fig.9 Reverse recovery parameter test circuit

Reverse Recovery Circuit

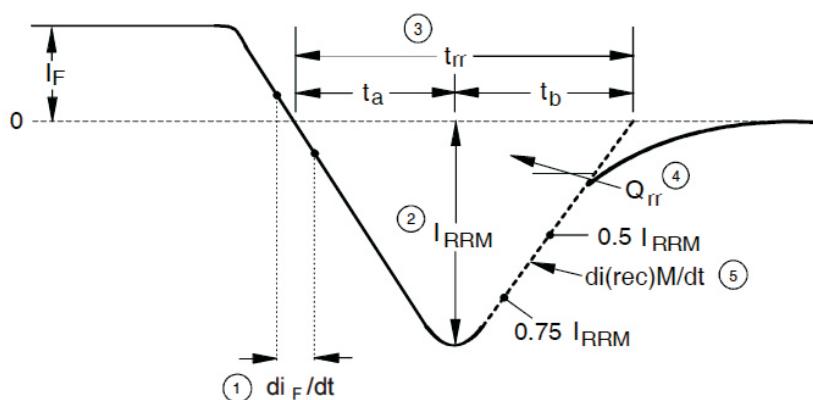


(3) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)}/D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1-D)$; $I_R @ V_{R1} = 80\% \text{ rated } V_R$

Fig.10 Reverse recovery waveform and definitions



1. di_F/dt - Rate of change of current through zero crossing

4. Q_{rr} - Area under curve defined by t_{rr} and I_{RRM}

2. I_{RRM} - Peak reverse recovery current

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

3. t_{rr} - Reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current

5. $di(\text{rec}) M / dt$ - Peak rate of change of current during t_b portion of t_{rr}

